

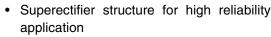
Vishay General Semiconductor

Miniature Glass Passivated Junction Plastic Rectifier



PRIMARY CHARACTERISTICS			
I _{F(AV)}	0.36 A		
V_{RRM}	1600 V		
I _{FSM}	15 A		
I _R	1.0 μΑ		
V _F at I _F = 2.0 A	1.6 V		
T _J max.	175 °C		

FEATURES





· Cavity-free glass-passivated junction

 0.36 A operation at T_A = 40 °C with no RoHS thermal runaway

COMPLIANT

- Typical I_R less than 0.1 μA
- Meets environmental standard MIL-S-19500
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in rectification of high voltage power supplies, inverters, converters and freewheeling application.

MECHANICAL DATA

Case: DO-204AL, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC-Q101 qualified), meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	BYX10GP	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	1600	V	
Maximum working reverse voltage	V_{RWM}	800	V	
Maximum average forward rectified current 0.375" (9.5 mm) lead length at T_A = 40 °C	I _{F(AV)}	0.36	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	15	А	
Operating junction and storage temperature range	T_J , T_{STG}	- 65 to + 175	°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	BYX10GP	UNIT
Maximum instantaneous forward voltage (1)	I _F = 2.0 A	T _A = 25 °C	V _F	1.6	V
Maximum peak reverse current at rated peak working reverse voltage (2)	V _{RWM} = 800 V	T _A = 25 °C	I _R	1.0	μΑ
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	2.0	μs
Typical junction capacitance	V _R = 4.0 V, 1 MHz		CJ	5.0	pF

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)				
PARAMETER	AMETER SYMBOL BYX10GP U			
Typical thermal resistance (1)	$R_{ hetaJA}$	45	°C/W	

Note:

(1) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
BYX10GP-E3/54	0.339	54	5500	13" diameter paper tape and reel	
BYX10GPHE3/54 (1)	0.339	54	5500	13" diameter paper tape and reel	

Note:

(1) Automotive grade AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

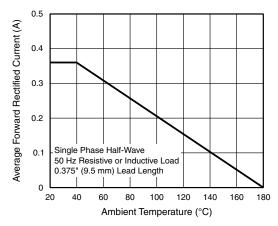


Figure 1. Forward Current Derating Curve

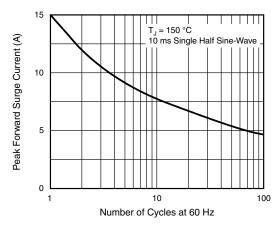


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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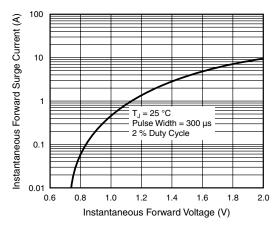


Figure 3. Typical Instantaneous Forward Characteristics

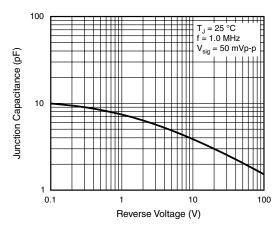


Figure 5. Typical Junction Capacitance

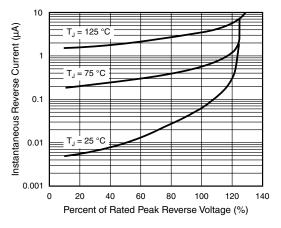


Figure 4. Typical Reverse Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-204AL (DO-41)

